

#### **50V NPN MEDIUM POWER TRANSISTOR IN TO252**

#### **Features**

- BV<sub>CEO</sub> > 50V
- I<sub>C</sub> = 2A Continuous Collector Current
- I<sub>CM</sub> = 3A Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
   The DIODES™ MJD2873Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

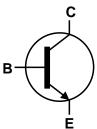
### **Mechanical Data**

- Package: TO252 (DPAK)
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>®</sup>
- Weight: 0.34 grams (Approximate)

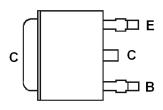




Top View



**Device Schematic** 



Pin Out Configuration Top View

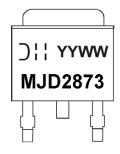
#### **Ordering Information** (Note 4)

Product	Packago	Package Marking Reel size (inches)		Tape width (mm)	Packing		
Froduct	Fackage			rape width (illin)	Qty.	Carrier	
MJD2873Q-13	TO252 (DPAK)	MJD2873	13	16	2,500	Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



MJD2873 = Product Type Marking Code

| Marking Code (101 – 102)

| Marking Code (101 – 103)



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	70	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	2	A
Peak Pulse Collector Current	I <sub>CM</sub>	3	А

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		2.60		
Power Dissipation	(Note 6)	$P_{D}$	2.30	W	
	(Note 7)		1.45		
	(Note 5)		48		
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	R <sub>0JA</sub> 54		°C/W
	(Note 7)		86		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

<sup>5.</sup> For a device mounted with the exposed collector pad on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

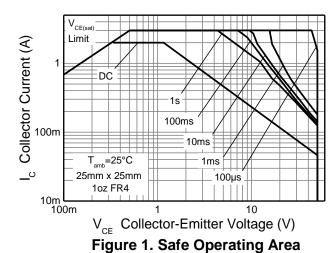
<sup>6.</sup> Same as note (5), except mounted on 25mm x 25mm 1oz copper.

<sup>7.</sup> Same as note (5), except mounted on minimum recommended pad (MRP) layout.

<sup>8.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



### **Thermal Characteristics**



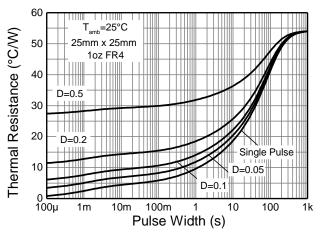
Max Power Dissipation (W) 2oz FR4 2.0 25mm x 25mm 1.5 1oz FR4 1.0 0.5 0.0 75 25 150 Temperature (°C)

25mm x 25mm

3.0

2.5

Figure 2. Derating Curve



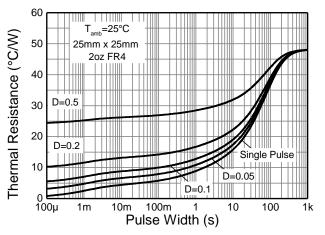


Figure 4. Transient Thermal Impedance

**Figure 3. Transient Thermal Impedance** 

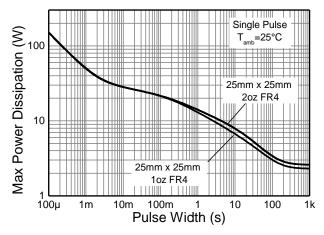


Figure 5. Pulse Power Dissipation



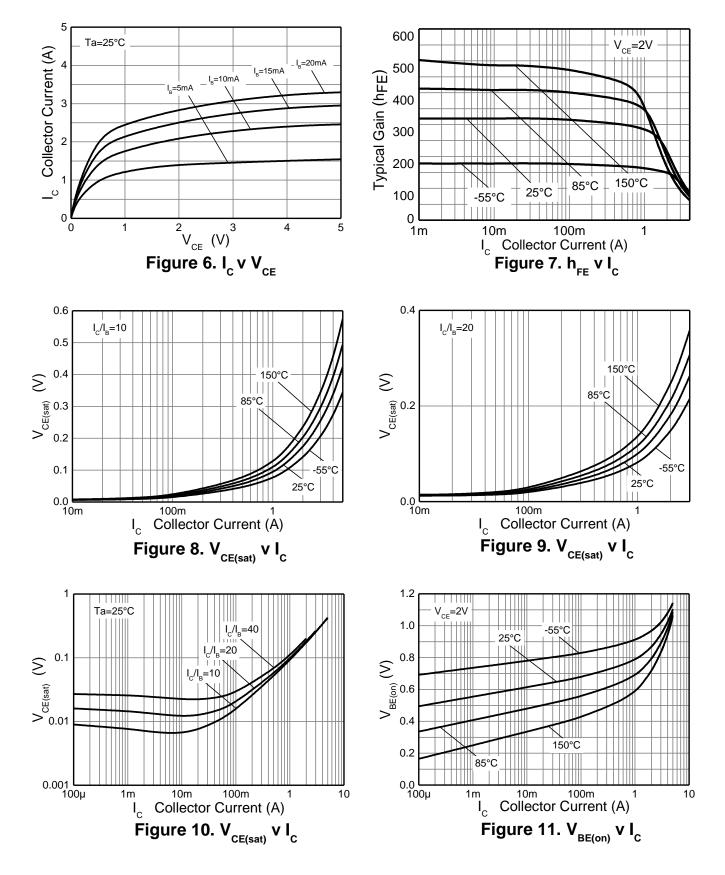
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	70	_	_	V	I <sub>C</sub> = 100uA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	50	_	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	_	_	V	I <sub>E</sub> = 100uA
Collector Cut-off Current	I <sub>CES</sub>		_	100	nA	$V_{CE} = 50V$
Collector-Base Cut-off Current	I <sub>CBO</sub>	_	_	100	nA	V <sub>CB</sub> = 70V
Emitter Cut-off Current	I <sub>EBO</sub>		_	100	nA	$V_{EB} = 6V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	_	0.3	V	$I_C = 1A$ , $I_B = 50mA$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	_	_	1.2	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 50mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	_	_	1.2 0.95	V	$I_C = 1A$ , $V_{CE} = 2V$ $I_C = 0.75A$ , $V_{CE} = 1.6V$
DC Current Gain (Note 9)	h <sub>FE</sub>	120 40 80			_	V <sub>CE</sub> = 2V, I <sub>C</sub> = 0.5A V <sub>CE</sub> = 2V, I <sub>C</sub> = 2A V <sub>CE</sub> = 1.6V, I <sub>C</sub> = 0.75A
Current Gain-Bandwidth Product	f⊤	65	_	_	MHz	$I_C = 0.1A$ , $V_{CE} = 10V$ , $f = 100MHz$
Output Capacitance	Cobo	_	26	_	pF	V <sub>CB</sub> = 10V, f = 1MHz
Input Capacitance	C <sub>ibo</sub>	_	45	_	pF	$V_{EB} = 0.5V$ , $f = 1MHz$
Delay Time	t <sub>d</sub>	_	29	_	ns	
Rise Time	t <sub>r</sub>		20		ns	$I_C = 0.5A, V_{CC} = 10V$
Storage Time	t <sub>s</sub>	_	378	_	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$
Fall Time	t <sub>f</sub>	_	57	_	ns	

Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ .



### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





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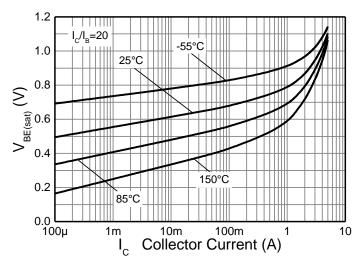


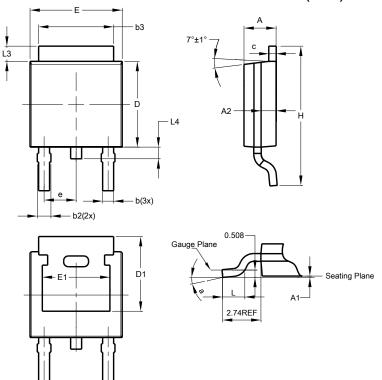
Figure 12.  $V_{BE(sat)} V I_{C}$ 



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO252 (DPAK)

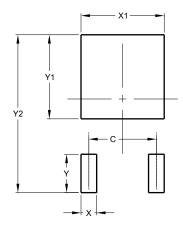


TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
<b>A</b> 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.50	5.33		
O	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21				
е	2.	286 BS	S		
Е	6.45	6.70	6.58		
E1	4.32				
Н	9.40	10.41	9.91		
٦	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°			
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO252 (DPAK)



Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
V2	10.700



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